

Description

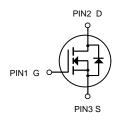
The DMN2065UW uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

 $V_{DS} = 20V I_{D} = 2A$

 $R_{DS(ON)}$ < 55m Ω @ V_{GS} =4.5V

 $R_{DS(ON)}$ < 85m Ω @ V_{GS} =2.5V



N-Channel MOSFET

Application

Battery protection

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
DMN2065UW	SOT-323	HXY MOSFET	3000

Absolute Maximum Ratings (T_A=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V _D s	Drain-Source Voltage	20	V
Vgs	Gate-Source Voltage	±12	V
I _D	Drain Current-Continuous	2	А
P _D	Maximum Power Dissipation	0.3	W
Т,,Тѕтс	Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}$
RеJA	Thermal Resistance,Junction-to-Ambient (Note 2)	125	°C/W

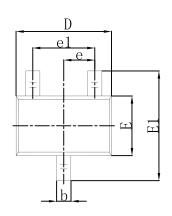
Electrical Characteristics (T_A=25°C unless otherwise noted)

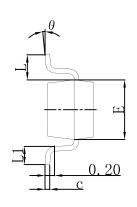
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
STATIC CHARACTERISTICE							
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	20			V	
Zero gate voltage drain current	I _{DSS}	V _{DS} =18V,V _{GS} = 0V			1	μΑ	
Gate-body leakage current	Igss	V _{GS} =±12V, V _{DS} = 0V			±100	nA	
Gate threshold voltage (note2)	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.4	0.7	1.0	V	
	R _{DS(on)}	V _{GS} =4.5V, I _D =2.0A			55	mΩ	
Drain-source on-resistance (note2)		V _{GS} =2.5V, I _D =0.3A			85	mΩ	
Maximum Continuous Drain to Source Diode Forward Current	Is				1.0	А	
Diode forward voltage	V _{SD}	I _S =1.0A, V _{GS} =0V			1.2	V	
DYNAMIC CHARACTERISTICS (note3)							
Input capacitance	C _{iss}			300		pF	
Output capacitance	Coss	V _{DS} =10V,V _{GS} =0V, f =1MHz		120		pF	
Reverse transfer capacitance	C _{rss}	1 - 1101112		80		pF	
SWITCHING CHARACTERISTICS (note3)							
Turn-on delay time	t _{d(on)}				15	nS	
Turn-on rise time	t _r	V _{GS} =4.5V,V _{DS} =10V,			85	nS	
Turn-off delay time	t _{d(off)}	R_L =5.1 Ω , R_G =5.1 Ω			65	nS	
Turn-off fall time	t _f				27	nS	

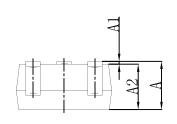
Notes:

- 1. Surface mounted on FR4 board using the minimum recommended pad size.
- 2. Pulse Test: Pulse Width=300µs, Duty Cycle=2%.
- 3. These parameters have no way to verify.

SOT-323 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650 TYP		0.026 TYP		
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.021 REF		
L1	0.260	0.460	0.010	0.018	
K	0°	8°	0°	8°	

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